



L Number	Hits	Search Text	DB	Time stamp
5	8	(("6004847") or ("5104819") or ("6274428")	USPAT	2002/11/04 09:43
		or ("6180457") or ("6429470") or		
		("6318267") or ("5572050") or		
		("4775549")).PN.		1
18	20	( ( ( ) ) ) ( ) ( ) ( ) ( ) ( ) ( ) ( )	USPAT;	2002/11/04 10:09
		same (ONO or (oxide adj nitride adj	US-PGPUB;	1
		oxide))) and (photoresist or mask)	EPO; JPO;	
			DERWENT;	
19	1.0	///000	IBM_TDB	
19	10	( ( ( ) =	USPAT;	2002/11/04 10:10
İ		same (ONO or (oxide adj nitride adj	US-PGPUB;	
		oxide))) and (photoresist or mask)) and semiconductor	EPO; JPO;	
		Semiconductor	DERWENT;	
24	191	(438/201).CCLS.	IBM_TDB USPAT;	2002/11/04 11:17
	131	(4307201):0010:	US-PGPUB;	2002/11/04 11:17
			EPO; JPO;	
			DERWENT;	
			IBM TDB	
-	3	(("6004847") or ("5104819") or	USPAT	2002/11/04 09:43
		("6274428")).PN.	JOINI	2002/11/04 09:43
-	524		USPAT;	2002/11/01 10:08
			US-PGPUB;	
F .			EPO; JPO;	
			DERWENT;	
			IBM TDB	
-	479	(438/258).CCLS.	USPAT;	2002/11/01 10:10
			US-PGPUB;	
	1		EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	271	(438/261).CCLS.	USPAT;	2002/11/01 10:10
			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
	1104	(430/257) 0010	IBM_TDB	
_	1104	(438/257).CCLS.	USPAT;	2002/11/01 10:10
			US-PGPUB;	
			EPO; JPO; DERWENT;	
			IBM TDB	
_	450	(438/756).CCLS.	USPAT;	2002/11/01 10:11
		(1-1)	US-PGPUB;	2002/11/01 10.11
			EPO; JPO;	
			DERWENT;	
			IBM TDB	
-	116	(438/757).CCLS.	USPAT;	2002/11/01 10:11
			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
		(400 (704)	IBM_TDB	
-	308	(438/724).CCLS.	USPAT;	2002/11/01 10:11
			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
1_	3039	139/255 259 201 261 257 756 757 704	IBM_TDB	2002/11/01 12 1-
	3039	438/255,258,201,261,257,756,757,724.ccls.	USPAT;	2002/11/01 10:15
			US-PGPUB;	
			EPO; JPO; DERWENT;	
_	14	438/255,258,201,261,257,756,757,724.ccls.	<pre>IBM_TDB USPAT;</pre>	2002/11/01 10:17
		and (ONS or (oxide adj nitride adj	US-PGPUB;	2002/11/01 10:1/
		silicon))	EPO; JPO;	
		, <i>,</i>	DERWENT;	
			IBM TDB	
				1

255,258,201,261,257,756,757,724.ccls.	USPAT;	2002/11/01 10:18
((ONS or (oxide adj nitride adj	US-PGPUB;	
.con)) same (ONO or (oxide adj nitride	EPO; JPO;	
oxide)))	DERWENT;	
	IBM TDB	
or (oxide adj nitride adj silicon))	USPAT;	2002/11/01 10:21

-	1	438/255,258,201,261,257,756,757,724.ccls.	USPAT;	2002/11/01	10:18
		and ((ONS or (oxide adj nitride adj	US-PGPUB;		
		silicon)) same (ONO or (oxide adj nitride	EPO; JPO;		
		adj oxide)))	DERWENT;		
	1		IBM_TDB		
-	24	, ,	USPAT;	2002/11/01	10:21
		same (ONO or (oxide adj nitride adj	US-PGPUB;		
		oxide))	EPO; JPO;		
			DERWENT;		
			IBM_TDB		
-	13	((ONS or (oxide adj nitride adj silicon))	USPAT;	2002/11/04	10:07
		same (ONO or (oxide adj nitride adj	US-PGPUB;		
:		oxide))) and semiconductor	EPO; JPO;		
	}		DERWENT;		
			IBM_TDB		

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